

# Dual 4-Input NAND Gates

## MC14012B

The MC14012B dual 4-input NAND gates are constructed with P-Channel and N-Channel enhancement mode devices in a single monolithic structure (Complementary MOS). Their primary use is where low power dissipation and/or high noise immunity is desired.

### Features

- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- All Outputs Buffered
- Capable of Driving Two Low-Power TTL Loads or One Low-Power Schottky TTL Load Over the Rated Temperature Range
- Double Diode Protection on All Inputs
- Pin-for-Pin Replacements for Corresponding CD4000 Series B Suffix Devices
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- This Device is Pb-Free and is RoHS Compliant

### MAXIMUM RATINGS (Voltages Referenced to $V_{SS}$ )

| Symbol            | Parameter                                         | Value                  | Unit |
|-------------------|---------------------------------------------------|------------------------|------|
| $V_{DD}$          | DC Supply Voltage Range                           | -0.5 to +18.0          | V    |
| $V_{in}, V_{out}$ | Input or Output Voltage Range (DC or Transient)   | -0.5 to $V_{DD} + 0.5$ | V    |
| $I_{in}, I_{out}$ | Input or Output Current (DC or Transient) per Pin | $\pm 10$               | mA   |
| $P_D$             | Power Dissipation, per Package (Note 1)           | 500                    | mW   |
| $T_A$             | Ambient Temperature Range                         | -55 to +125            | °C   |
| $T_{stg}$         | Storage Temperature Range                         | -65 to +150            | °C   |
| $T_L$             | Lead Temperature (8-Second Soldering)             | 260                    | °C   |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: "D/DW" Package: -7.0 mW/°C From 65 °C To 125 °C

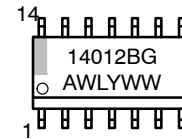
This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$ .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$  or  $V_{DD}$ ). Unused outputs must be left open.



SOIC-14  
D SUFFIX  
CASE 751A

### MARKING DIAGRAM



A = Assembly Location  
WL, L = Wafer Lot  
YY, Y = Year  
WW, W = Work Week  
G = Pb-Free Package

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

# MC14012B

## MC14012B Dual 4-Input NAND Gate

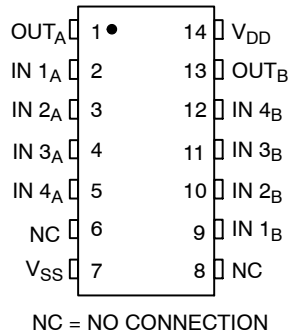


Figure 1. Pin Assignment

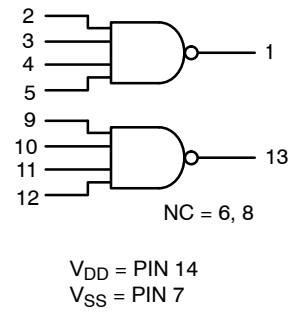


Figure 2. Logic Diagram

### ORDERING INFORMATION

| Device        | Package              | Shipping <sup>†</sup>    |
|---------------|----------------------|--------------------------|
| MC14012BDG    | SOIC-14<br>(Pb-Free) | 55 Units / Rail          |
| MC14012BDR2G  | SOIC-14<br>(Pb-Free) | 2500 Units / Tape & Reel |
| NLV14012BDR2G | SOIC-14<br>(Pb-Free) | 2500 Units / Tape & Reel |

### DISCONTINUED (Note 2)

| Device      | Package              | Shipping <sup>†</sup> |
|-------------|----------------------|-----------------------|
| NLV14012BDG | SOIC-14<br>(Pb-Free) | 55 Units / Rail       |

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

2. **DISCONTINUED:** This device is not recommended for new design. Please contact your **onsemi** representative for information. The most current information on this device may be available on [www.onsemi.com](http://www.onsemi.com).

# MC14012B

## ELECTRICAL CHARACTERISTICS (Voltages Referenced to V<sub>SS</sub>)

| Characteristic                                                                                                                                    | Symbol                    | V <sub>DD</sub><br>Vdc | –55°C                                                |       | 25°C  |                 |       | 125°C |      | Unit |
|---------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------|------------------------|------------------------------------------------------|-------|-------|-----------------|-------|-------|------|------|
|                                                                                                                                                   |                           |                        | Min                                                  | Max   | Min   | Typ<br>(Note 3) | Max   | Min   | Max  |      |
| Output Voltage<br>V <sub>in</sub> = V <sub>DD</sub> or 0                                                                                          | V <sub>OL</sub>           | 5.0                    | –                                                    | 0.05  | –     | 0               | 0.05  | –     | 0.05 | Vdc  |
| V <sub>in</sub> = 0 or V <sub>DD</sub>                                                                                                            |                           | 10                     | –                                                    | 0.05  | –     | 0               | 0.05  | –     | 0.05 |      |
|                                                                                                                                                   |                           | 15                     | –                                                    | 0.05  | –     | 0               | 0.05  | –     | 0.05 |      |
|                                                                                                                                                   | V <sub>OH</sub>           | 5.0                    | 4.95                                                 | –     | 4.95  | 5.0             | –     | 4.95  | –    | Vdc  |
| 10                                                                                                                                                |                           | 9.95                   | –                                                    | 9.95  | 10    | –               | 9.95  | –     |      |      |
| 15                                                                                                                                                |                           | 14.95                  | –                                                    | 14.95 | 15    | –               | 14.95 | –     |      |      |
| Input Voltage<br>(V <sub>O</sub> = 4.5 or 0.5 Vdc)<br>(V <sub>O</sub> = 9.0 or 1.0 Vdc)<br>(V <sub>O</sub> = 13.5 or 1.5 Vdc)                     | V <sub>IL</sub>           | 5.0                    | –                                                    | 1.5   | –     | 2.25            | 1.5   | –     | 1.5  | Vdc  |
| V <sub>IH</sub>                                                                                                                                   |                           | 10                     | –                                                    | 3.0   | –     | 4.50            | 3.0   | –     | 3.0  |      |
|                                                                                                                                                   |                           | 15                     | –                                                    | 4.0   | –     | 6.75            | 4.0   | –     | 4.0  |      |
|                                                                                                                                                   | V <sub>IH</sub>           | 5.0                    | 3.5                                                  | –     | 3.5   | 2.75            | –     | 3.5   | –    | Vdc  |
| 10                                                                                                                                                |                           | 7.0                    | –                                                    | 7.0   | 5.50  | –               | 7.0   | –     |      |      |
| 15                                                                                                                                                |                           | 11                     | –                                                    | 11    | 8.25  | –               | 11    | –     |      |      |
| Output Drive Current<br>(V <sub>OH</sub> = 2.5 Vdc)<br>(V <sub>OH</sub> = 4.6 Vdc)<br>(V <sub>OH</sub> = 9.5 Vdc)<br>(V <sub>OH</sub> = 13.5 Vdc) | Source<br>I <sub>OH</sub> | 5.0                    | –3.0                                                 | –     | –2.4  | –4.2            | –     | –1.7  | –    | mAdc |
| 5.0                                                                                                                                               |                           | –0.64                  | –                                                    | –0.51 | –0.88 | –               | –0.36 | –     |      |      |
| 10                                                                                                                                                |                           | –1.6                   | –                                                    | –1.3  | –2.25 | –               | –0.9  | –     |      |      |
| 15                                                                                                                                                |                           | –4.2                   | –                                                    | –3.4  | –8.8  | –               | –2.4  | –     |      |      |
| (V <sub>OL</sub> = 0.4 Vdc)<br>(V <sub>OL</sub> = 0.5 Vdc)<br>(V <sub>OL</sub> = 1.5 Vdc)                                                         | Sink<br>I <sub>OL</sub>   | 5.0                    | 0.64                                                 | –     | 0.51  | 0.88            | –     | 0.36  | –    | mAdc |
| 10                                                                                                                                                |                           | 1.6                    | –                                                    | 1.3   | 2.25  | –               | 0.9   | –     |      |      |
| 15                                                                                                                                                |                           | 4.2                    | –                                                    | 3.4   | 8.8   | –               | 2.4   | –     |      |      |
| Input Current                                                                                                                                     | I <sub>in</sub>           | 15                     | –                                                    | ±0.1  | –     | ±0.00001        | ±0.1  | –     | ±1.0 | μAdc |
| Input Capacitance<br>(V <sub>in</sub> = 0)                                                                                                        | C <sub>in</sub>           | –                      | –                                                    | –     | –     | 5.0             | 7.5   | –     | –    | pF   |
| Quiescent Current<br>(Per Package)                                                                                                                | I <sub>DD</sub>           | 5.0                    | –                                                    | 0.25  | –     | 0.0005          | 0.25  | –     | 7.5  | μAdc |
|                                                                                                                                                   |                           | 10                     | –                                                    | 0.5   | –     | 0.0010          | 0.5   | –     | 15   |      |
|                                                                                                                                                   |                           | 15                     | –                                                    | 1.0   | –     | 0.0015          | 1.0   | –     | 30   |      |
| Total Supply Current (Notes 4, 5)<br>(Dynamic plus Quiescent,<br>Per Gate, C <sub>L</sub> = 50 pF)                                                | I <sub>T</sub>            | 5.0                    | I <sub>T</sub> = (0.3 μA/kHz) f + I <sub>DD</sub> /N |       |       |                 |       |       |      | μAdc |
|                                                                                                                                                   |                           | 10                     | I <sub>T</sub> = (0.6 μA/kHz) f + I <sub>DD</sub> /N |       |       |                 |       |       |      |      |
|                                                                                                                                                   |                           | 15                     | I <sub>T</sub> = (0.9 μA/kHz) f + I <sub>DD</sub> /N |       |       |                 |       |       |      |      |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

4. The formulas given are for the typical characteristics only at 25 °C.

5. To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) Vfk$$

where: I<sub>T</sub> is in μA (per package), C<sub>L</sub> in pF, V = (V<sub>DD</sub> – V<sub>SS</sub>) in volts, f in kHz is input frequency, and k = 0.001 x the number of exercised gates per package.

# MC14012B

## SWITCHING CHARACTERISTICS (Note 6) ( $C_L = 50 \text{ pF}$ , $T_A = 25^\circ \text{C}$ )

| Characteristic                                                                                                                                                                                                             | Symbol             | $V_{DD}$<br>Vdc | Min         | Typ<br>(Note 7) | Max               | Unit |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------|-----------------|-------------|-----------------|-------------------|------|
| Output Rise Time<br>$t_{TLH} = (1.35 \text{ ns/pF}) C_L + 33 \text{ ns}$<br>$t_{TLH} = (0.60 \text{ ns/pF}) C_L + 20 \text{ ns}$<br>$t_{TLH} = (0.40 \text{ ns/pF}) C_L + 20 \text{ ns}$                                   | $t_{TLH}$          | 5.0<br>10<br>15 | –<br>–<br>– | 100<br>50<br>40 | 200<br>100<br>80  | ns   |
| Output Fall Time<br>$t_{THL} = (1.35 \text{ ns/pF}) C_L + 33 \text{ ns}$<br>$t_{THL} = (0.60 \text{ ns/pF}) C_L + 20 \text{ ns}$<br>$t_{THL} = (0.40 \text{ ns/pF}) C_L + 20 \text{ ns}$                                   | $t_{THL}$          | 5.0<br>10<br>15 | –<br>–<br>– | 100<br>50<br>40 | 200<br>100<br>80  | ns   |
| Propagation Delay Time<br>$t_{PLH}, t_{PHL} = (0.90 \text{ ns/pF}) C_L + 115 \text{ ns}$<br>$t_{PLH}, t_{PHL} = (0.36 \text{ ns/pF}) C_L + 47 \text{ ns}$<br>$t_{PLH}, t_{PHL} = (0.26 \text{ ns/pF}) C_L + 37 \text{ ns}$ | $t_{PLH}, t_{PHL}$ | 5.0<br>10<br>15 | –<br>–<br>– | 160<br>65<br>50 | 300<br>130<br>100 | ns   |

6. The formulas given are for the typical characteristics only at  $25^\circ \text{C}$ .

7. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

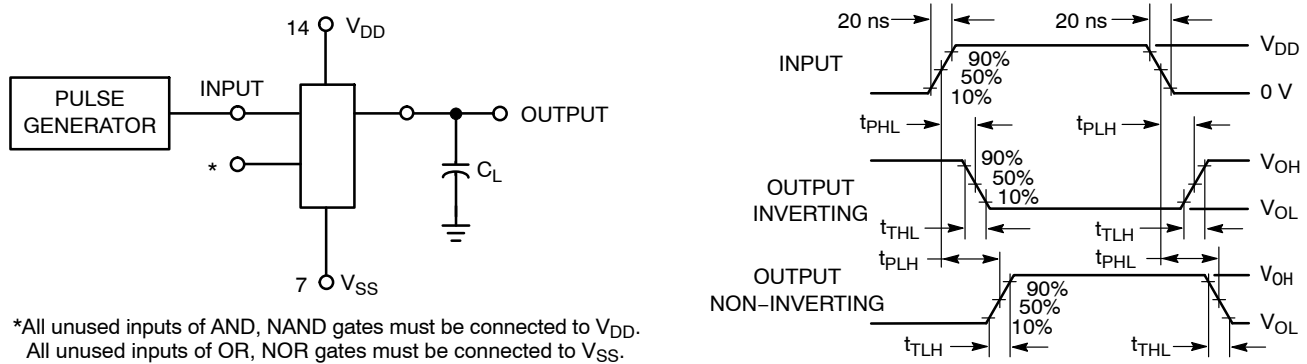


Figure 3. Switching Time Test Circuit and Waveforms

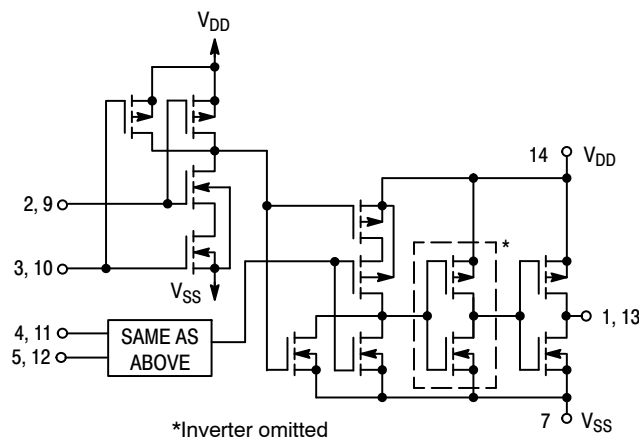
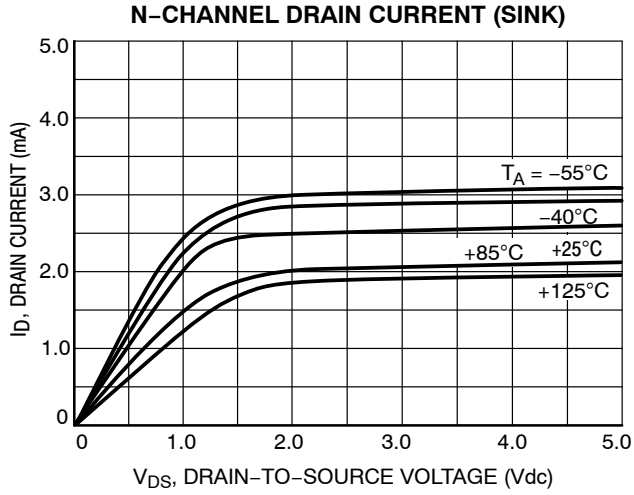
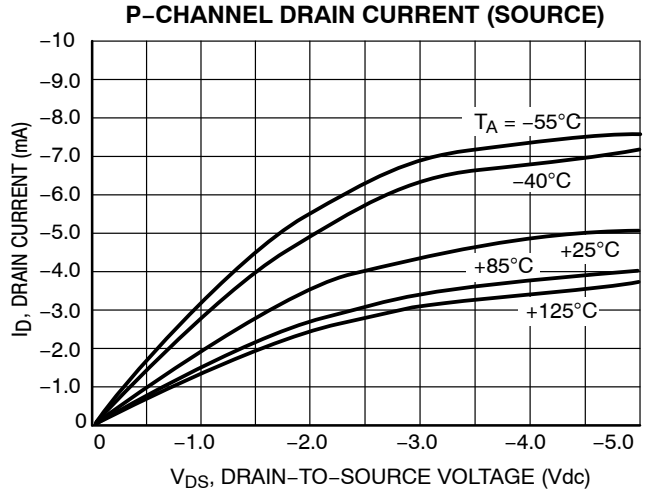
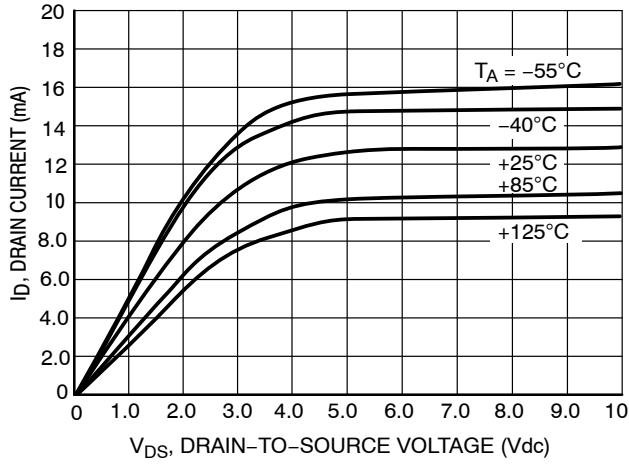
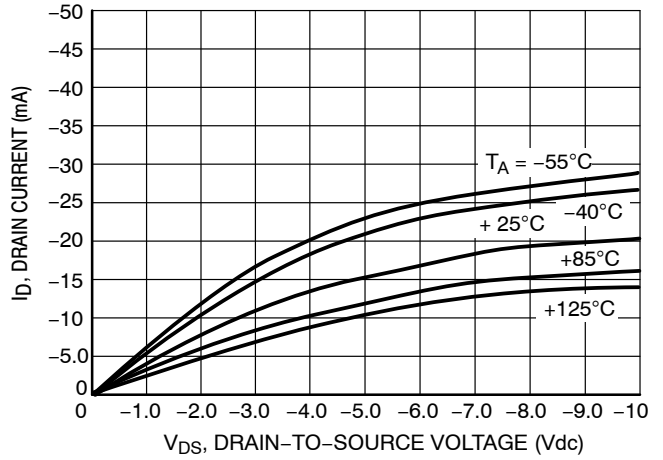
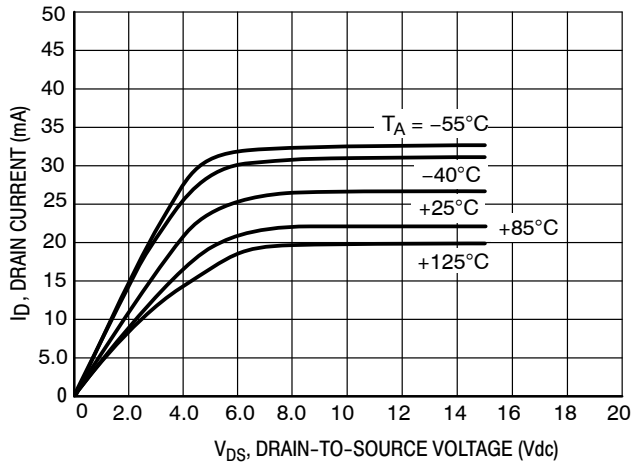
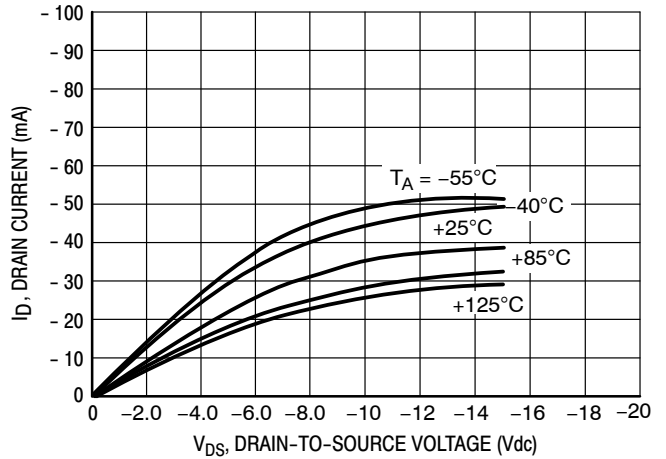


Figure 4. Circuit Schematic – One of Two Gates Shown

## TYPICAL B-SERIES GATE CHARACTERISTICS

Figure 5.  $V_{GS} = 5.0$  VdcFigure 6.  $V_{GS} = -5.0$  VdcFigure 7.  $V_{GS} = 10$  VdcFigure 8.  $V_{GS} = -10$  VdcFigure 9.  $V_{GS} = 15$  VdcFigure 10.  $V_{GS} = -15$  Vdc

These typical curves are not guarantees, but are design aids.  
Caution: The maximum rating for output current is 10 mA per pin.

VOLTAGE TRANSFER CHARACTERISTICS

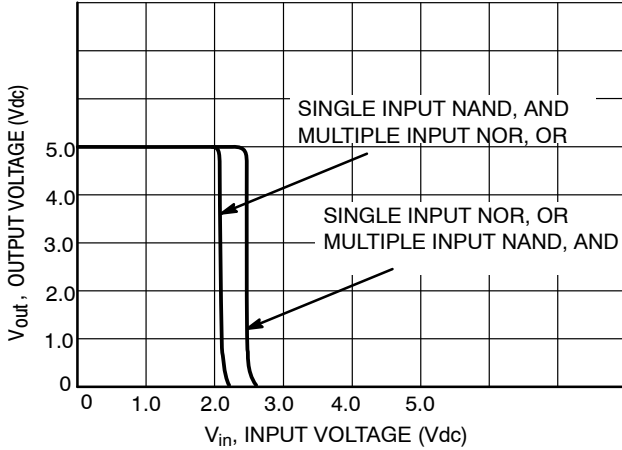


Figure 11.  $V_{DD} = 5.0 \text{ Vdc}$

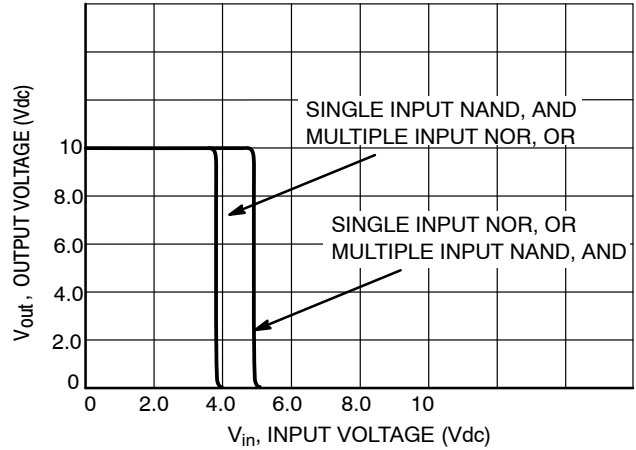


Figure 12.  $V_{DD} = 10 \text{ Vdc}$

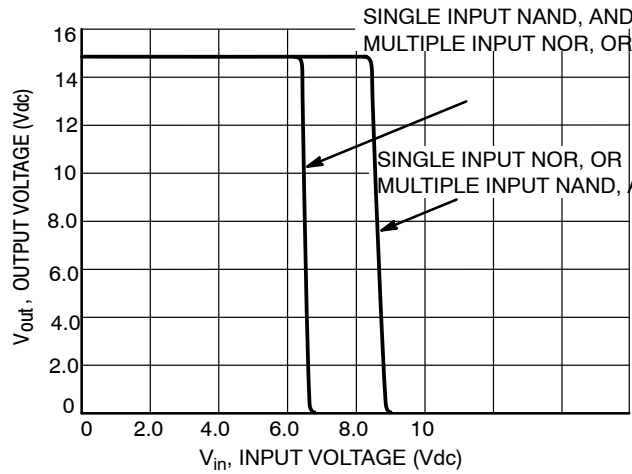


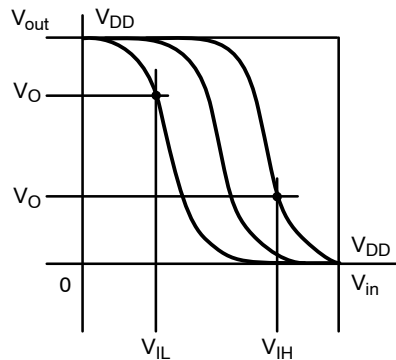
Figure 13.  $V_{DD} = 15 \text{ Vdc}$

DC NOISE MARGIN

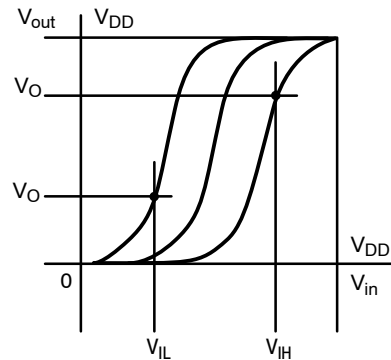
The DC noise margin is defined as the input voltage range from an ideal “1” or “0” input level which does not produce output state change(s). The typical and guaranteed limit values of the input values  $V_{IL}$  and  $V_{IH}$  for the output(s) to be at a fixed voltage  $V_O$  are given in the Electrical Characteristics table.  $V_{IL}$  and  $V_{IH}$  are presented graphically in Figure 11.

Guaranteed minimum noise margins for both the “1” and “0” levels =

- 1.0 V with a 5.0 V supply
- 2.0 V with a 10.0 V supply
- 2.5 V with a 15.0 V supply



(a) Inverting Function



(b) Non-Inverting Function

Figure 14. DC Noise Immunity

## MC14012B

### REVISION HISTORY

| Revision | Description of Changes                                                                    | Date      |
|----------|-------------------------------------------------------------------------------------------|-----------|
| 12       | NLV14012BDG OPN Marked as Discontinued + Rebranded the Data Sheet to <b>onsemi</b> format | 7/11/2025 |

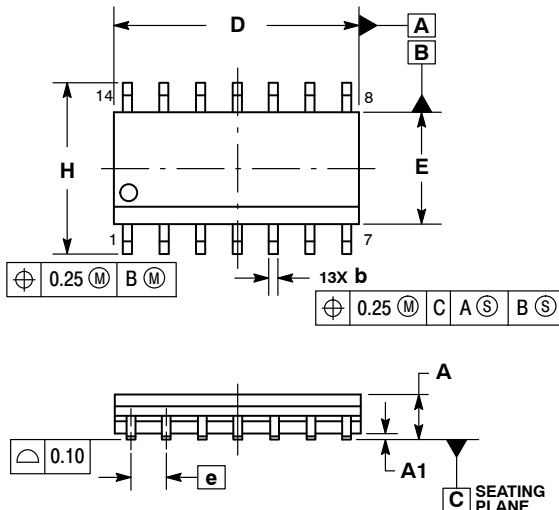
This document has undergone updates prior to the inclusion of this revision history table. The changes tracked here only reflect updates made on the noted approval dates.



SCALE 1:1

SOIC-14 NB  
CASE 751A-03  
ISSUE L

DATE 03 FEB 2016

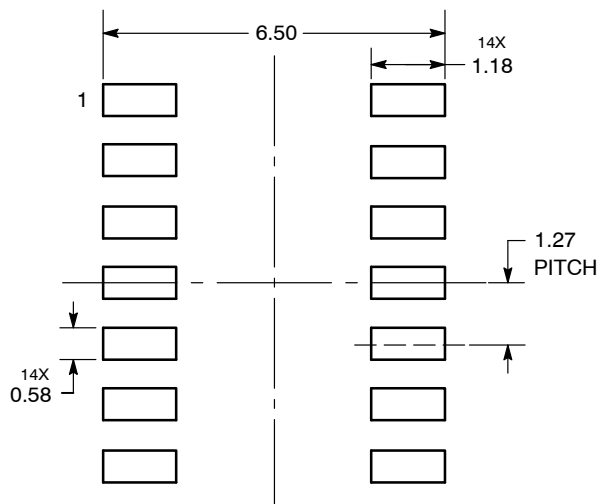


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT MAXIMUM MATERIAL CONDITION.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.
5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.

| DIM | MILLIMETERS |      | INCHES    |       |
|-----|-------------|------|-----------|-------|
|     | MIN         | MAX  | MIN       | MAX   |
| A   | 1.35        | 1.75 | 0.054     | 0.068 |
| A1  | 0.10        | 0.25 | 0.004     | 0.010 |
| A3  | 0.19        | 0.25 | 0.008     | 0.010 |
| b   | 0.35        | 0.49 | 0.014     | 0.019 |
| D   | 8.55        | 8.75 | 0.337     | 0.344 |
| E   | 3.80        | 4.00 | 0.150     | 0.157 |
| e   | 1.27 BSC    |      | 0.050 BSC |       |
| H   | 5.80        | 6.20 | 0.228     | 0.244 |
| h   | 0.25        | 0.50 | 0.010     | 0.019 |
| L   | 0.40        | 1.25 | 0.016     | 0.049 |
| M   | 0°          | 7°   | 0°        | 7°    |

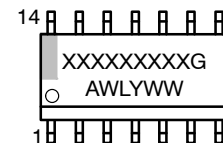
SOLDERING FOOTPRINT\*



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC  
MARKING DIAGRAM\*



XXXXXX = Specific Device Code  
A = Assembly Location  
WL = Wafer Lot  
Y = Year  
WW = Work Week  
G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

|                  |             |                                                                                                                                                                                     |
|------------------|-------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| DOCUMENT NUMBER: | 98ASB42565B | Electronic versions are uncontrolled except when accessed directly from the Document Repository.<br>Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. |
| DESCRIPTION:     | SOIC-14 NB  | PAGE 1 OF 2                                                                                                                                                                         |

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SOIC-14  
CASE 751A-03  
ISSUE L

DATE 03 FEB 2016

STYLE 1:  
PIN 1. COMMON CATHODE  
2. ANODE/CATHODE  
3. ANODE/CATHODE  
4. NO CONNECTION  
5. ANODE/CATHODE  
6. NO CONNECTION  
7. ANODE/CATHODE  
8. ANODE/CATHODE  
9. ANODE/CATHODE  
10. NO CONNECTION  
11. ANODE/CATHODE  
12. ANODE/CATHODE  
13. NO CONNECTION  
14. COMMON ANODE

STYLE 2:  
CANCELLED

STYLE 3:  
PIN 1. NO CONNECTION  
2. ANODE  
3. ANODE  
4. NO CONNECTION  
5. ANODE  
6. NO CONNECTION  
7. ANODE  
8. ANODE  
9. ANODE  
10. NO CONNECTION  
11. ANODE  
12. ANODE  
13. NO CONNECTION  
14. COMMON CATHODE

STYLE 4:  
PIN 1. NO CONNECTION  
2. CATHODE  
3. CATHODE  
4. NO CONNECTION  
5. CATHODE  
6. NO CONNECTION  
7. CATHODE  
8. CATHODE  
9. CATHODE  
10. NO CONNECTION  
11. CATHODE  
12. CATHODE  
13. NO CONNECTION  
14. COMMON ANODE

STYLE 5:  
PIN 1. COMMON CATHODE  
2. ANODE/CATHODE  
3. ANODE/CATHODE  
4. ANODE/CATHODE  
5. ANODE/CATHODE  
6. NO CONNECTION  
7. COMMON ANODE  
8. COMMON CATHODE  
9. ANODE/CATHODE  
10. ANODE/CATHODE  
11. ANODE/CATHODE  
12. ANODE/CATHODE  
13. NO CONNECTION  
14. COMMON ANODE

STYLE 6:  
PIN 1. CATHODE  
2. CATHODE  
3. CATHODE  
4. CATHODE  
5. CATHODE  
6. CATHODE  
7. CATHODE  
8. ANODE  
9. ANODE  
10. ANODE  
11. ANODE  
12. ANODE  
13. ANODE  
14. ANODE

STYLE 7:  
PIN 1. ANODE/CATHODE  
2. COMMON ANODE  
3. COMMON CATHODE  
4. ANODE/CATHODE  
5. ANODE/CATHODE  
6. ANODE/CATHODE  
7. ANODE/CATHODE  
8. ANODE/CATHODE  
9. ANODE/CATHODE  
10. ANODE/CATHODE  
11. COMMON CATHODE  
12. COMMON ANODE  
13. ANODE/CATHODE  
14. ANODE/CATHODE

STYLE 8:  
PIN 1. COMMON CATHODE  
2. ANODE/CATHODE  
3. ANODE/CATHODE  
4. NO CONNECTION  
5. ANODE/CATHODE  
6. ANODE/CATHODE  
7. COMMON ANODE  
8. COMMON ANODE  
9. ANODE/CATHODE  
10. ANODE/CATHODE  
11. NO CONNECTION  
12. ANODE/CATHODE  
13. ANODE/CATHODE  
14. COMMON CATHODE

|                  |             |                                                                                                                                                                                     |
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| DESCRIPTION:     | SOIC-14 NB  | PAGE 2 OF 2                                                                                                                                                                         |

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